

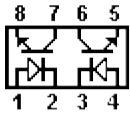
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ISD201 OPTICALLY COUPLED ISOLATORS

Circuit



Features

- 5000 V Isolation.
- High Current Transfer Ratio 75% min.
- Low Cost Dual-In-Line Package.
- Dual Configuration.

Description

The ISD201 is an optically coupled isolator. Each channel consists of a Gallium Arsenide infrared emitting diode and an NPN silicon phototransistor mounted in a standard 6-pin dual-in-line package. Surface Mount Option Available.

The ISD201 offers two channels per unit.

All electrical parameters are 100% tested by manufacturing. Specifications are guaranteed to a cumulative 0.65% AQL.

Absolute Maximum Ratings (Ta=25°C)

Storage Temperature:	-55°C to +150°C
Operating Temperature:	-55°C to +100°C
Lead Soldering:	260°C for 10s, 1.6mm from case
Input-to-Output Isolation Voltage:	±5000Vdc (note 1)

Input Diode

Forward DC Current:	60mA
Reverse DC Voltage:	3V
Peak Forward Current:	1A (PW.=100µs, duty ratio 0.001)
Power Dissipation:	100mW
Derate Linearly:	1.33mW/°C above 25°C

Output Transistor

Collector-Emitter Voltage:	30V
Emitter-Collector Voltage:	7V
Power Dissipation:	150mW
Derate Linearly:	2.00mW/°C above 25°C

Package

Total Power Dissipation:	400mW
Derate Linearly:	5.33mW/°C above 25°C

Electro-optical Characteristics (Ta=25°C)

INPUT	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _F	Forward Current	I _F =20mA		1.2	1.5	V
		I _F =1mA		1	1.2	
I _R	Reverse Current	V _R =3V			10	µA
OUTPUT						
H _{FE}		I _C =100µA, V _{CE} =5V	100	200		V
BV _{CEO}	Collector-Emitter Voltage	I _C =1mA	30	50		V
BV _{ECO}	Emitter-Collector Voltage	I _E =0.1mA	7	9		V
I _{CEO}	Collector-Emitter Dark Current	V _{CE} =10V			50	nA
COUPLED PARAMETER						
CTR	DC Current Transfer Ratio	I _F =10mA, V _{CE} =10V	75			%
CTR	DC Current Transfer Ratio	I _F =1mA, V _{CE} =10V	10	20		%
V _{CE(SAT)}	Collector-Emitter Saturation Voltage	I _F =10mA, I _C =2.0mA		0.2	0.4	V
C _F	Floating Capacitance	V=0, f=1MHz		0.6	1	pF
	Input-Output Isolation Resistance	V _{IO} =500V, (note 1)	5E11			ohm

Notes

1. Measured with input leads shorted together and output leads shorted together.

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